



6-BIT, 1-of-2 MULTIPLEXER/DEMULITPLEXER WITH INTEGRATED IEC L-4 ESD AND 1.8V LOGIC COMPATIBLE CONTROL INPUTS

■ DESCRIPTION

The UTC **UMDM27518** is a 6-bit 1-of-2 high-speed multiplexer/demultiplexer operating from 1.65V to 3.6V. Both digital and analog signals can be handled, and signals up to V₊ can be transmitted in either direction.

The UTC **UMDM27518** has two control pins working separately, each controlling three 1-of-2 multiplexers at the same time. One enable pin is used to put all outputs in high-impedance mode. The control pins are compatible with 1.8V logic thresholds and are backward compatible with 2.5V and 3.3V logic thresholds as well.

The UTC **UMDM27518** allows any SD, SDIO, and multimedia card host controllers to be expanded out to multiple cards or peripherals since the SDIO interface consists of 6-bits: CMD, CLK, and Data [0:3] signals. The UTC **UMDM27518** has two control pins that give additional flexibility to the user. For example, the ability to mux two different audio-video signals in equipment such as an LCD television, an LCD monitor, or a notebook docking station.

■ FEATURES

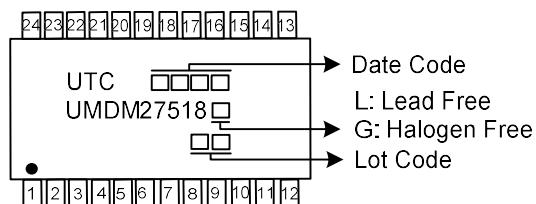
- * 1.65V~3.6V Single-Supply Operation
- * Bandwidth up to 240MHz for High-Speed Rail-to-Rail Signal Handling
- * Low Capacitance Switches, 21.5pF (Typical)
- * Isolation in Powerdown Mode, V₊=0
- * 1.8V Logic Threshold Compatibility for Control Inputs
- * 3.6V Tolerant Control Inputs
- * Crosstalk and Off Isolation of -62dB

■ ORDERING INFORMATION

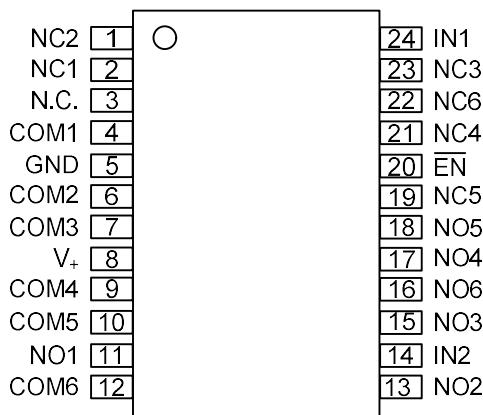
Ordering Number		Package	Packing
Lead Free	Halogen Free		
UMDM27518L-P24-R	UMDM27518G-P24-R	TSSOP-24	Tape Reel

UMDM27518G-P24-R	(1)Packing Type (2)Package Type (3)Green Package	(1) R: Tape Reel (2) P24: TSSOP-24 (3) G: Halogen Free and Lead Free, L: Lead Free
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■ MARKING



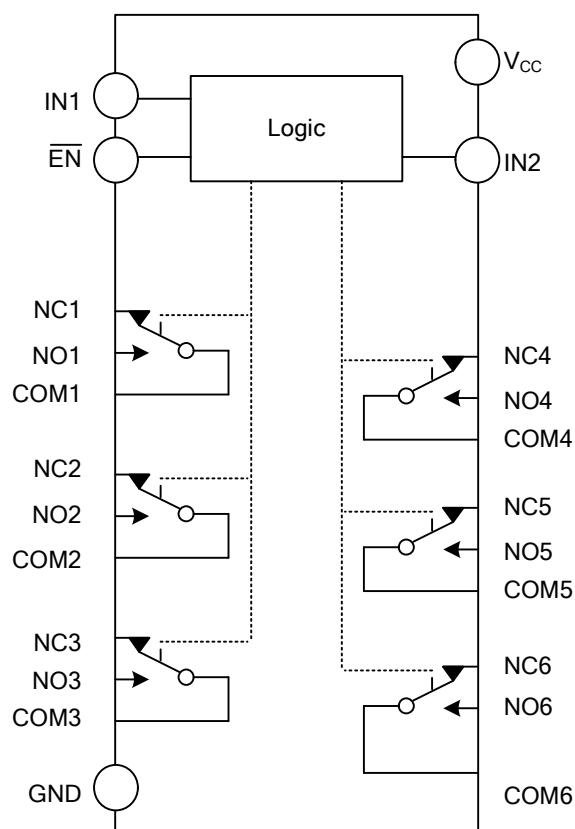
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	NC2	NC Port for BIT 2.
2	NC1	NC Port for BIT 1.
3	N.C.	No Connection.
4	COM1	Common Port for BIT 1.
5	GND	Ground.
6	COM2	Common Port for BIT 2.
7	COM3	Common Port for BIT 3.
8	V ₊	Power Supply.
9	COM4	Common Port for BIT 4.
10	COM5	Common Port for BIT 5.
11	NO1	NO Port for BIT 1.
12	COM6	Common Port for BIT 6.
13	NO2	NO Port for BIT 2.
14	IN2	Control BIT 4, 5, 6
15	NO3	NO Port for BIT 3.
16	NO6	NO Port for BIT 6.
17	NO4	NO Port for BIT 4.
18	NO5	NO Port for BIT 1.
19	NC5	NC Port for BIT 5.
20	EN	Enable.
21	NC4	NC Port for BIT 4.
22	NC6	NC Port for BIT 6.
23	NC3	NC Port for BIT 3.
24	IN1	Control BIT 1, 2, 3

■ LOGIC DIAGRAM



■ FUNCTION TABLE

\overline{EN}	IN1	IN2	NC1/2/3 TO COM1/2/3 COM1/2/3 TO NC1/2/3	NC4/5/6 TO COM4/5/6 COM4/5/6 TO NC4/5/6	NO1/2/3 TO COM1/2/3 COM1/2/3 TO NO1/2/3	NO4/5/6 TO COM4/5/6 COM4/5/6 TO NO4/5/6
H	X	X	OFF	OFF	OFF	OFF
L	L	L	ON	ON	OFF	OFF
L	H	L	OFF	ON	ON	OFF
L	L	H	ON	OFF	OFF	ON
L	H	H	OFF	OFF	ON	ON

Note: H: HIGH voltage level, L: LOW voltage level, X = Don't Care.

■ ABSOLUTE MAXIMUM RATINGS

(Over operating free-air temperature range, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage Range (Note 2)		V ₊	-0.5 ~ 4.6	V
Analog Voltage Range (Note 2, 3)		V _{NC} , V _{NO} , V _{COM}	-0.5 ~ 4.6	V
Analog Port Diode Current (Note 4)	V ₊ <V _{NC} , V _{NO} , V _{COM} <0	I _K	-50	mA
ON-state Switch Current (Note 5)	V _{NC} , V _{NO} , V _{COM} =0~V ₊	I _{NC} , I _{NO} , I _{COM}	-50 ~ 50	mA
Digital Input Voltage Range (Note 2, 3)	V _I	-0.5 ~ 4.6	V	
Digital Input Clamp Current (Note 2, 3)	V _{IO} <V _I <0	I _{IK}	-50	mA
Continuous Current Through V ₊	I ₊	100	mA	
Continuous Current Through GND	I _{GND}	-100	mA	
Storage Temperature Range	T _{STG}	-65 ~ +150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. All voltages are with respect to ground, unless otherwise specified.
3. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
4. Requires clamp diodes on analog port to V₊.
5. Pulse at 1ms duration < 10% duty cycle.

■ ELECTRICAL CHARACTERISTICS FOR 3.3V SUPPLY (Note 1)

(V₊=3V~3.6V, T_A=-40°C~85°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
ANALOG SWITCH								
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V ₊		Ω
ON-state Resistance	R _{ON}	0≤(V _{NC} or V _{NO})≤V ₊ , I _{COM} =-32mA, Switch ON, See Figure 1	25°C	3V	4.4	6.2	Ω	
			Full					
ON-state Resistance Match Between Channels	ΔR _{ON}	V _{NC} or V _{NO} =2.1V, I _{COM} =-32mA, Switch ON, See Figure 1	25°C	3V	0.3	0.7	Ω	
			Full					
ON-state Resistance Flatness	R _{ON} (FLAT)	0≤(V _{NC} or V _{NO})≤V ₊ , I _{COM} =-32mA, Switch ON, See Figure 1	25°C	3V	0.95	2.1	Ω	
			Full					
NC, NO OFF Leakage Current	I _{NC} (OFF), I _{NO} (OFF)	V _{NC} or V _{NO} =1V, V _{COM} =3V, or V _{NC} or V _{NO} =3V, V _{COM} =1V, Switch OFF, See Figure 2	25°C	3.6V	-0.5	0.05	0.5	μA
			Full		-7		7	μA
	I _{NC} (PWROFF), I _{NO} (PWROFF)	V _{NC} or V _{NO} =0~3.6V, V _{COM} =3.6V~0, or V _{NC} or V _{NO} =3.6V~0, V _{COM} =0~3.6V, Switch OFF, See Figure 2	25°C	0V	-1	0.05	1	μA
			Full		-12		12	μA

ELECTRICAL CHARACTERISTICS FOR 3.3V SUPPLY (Cont.)

(V₊=3V~3.6V, T=-40°C~85°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
COM OFF Leakage Current	I _{COM} (OFF)	V _{NC} or V _{NO} =3V, V _{COM} =1V, or V _{NC} or V _{NO} =1V, V _{COM} =3V, Switch OFF, See Figure 2	25°C	3.6V	-1	0.01	1	μA
			Full		-2		2	μA
	I _{COM} (PWROFF)	V _{NC} or V _{NO} =3.6V~0, V _{COM} =0~3.6V, or V _{NC} or V _{NO} =0~3.6V, V _{COM} =3.6V~0, Switch OFF, See Figure 2	25°C	0V	-1	0.02	1	μA
			Full		-12		1	
NC, NO ON Leakage Current	I _{NO} (ON), I _{NC} (ON)	V _{NC} or V _{NO} =1V, V _{COM} =Open, or V _{NC} or V _{NO} =3V, V _{COM} =Open, Switch ON, See Figure 3	25°C	3.6V	-2.5	0.04	2.2	μA
			Full		-7		7	μA
COM ON Leakage Current	I _{COM} (ON)	V _{NC} or V _{NO} =Open, V _{COM} =1V, or V _{NC} or V _{NO} =Open, V _{COM} =3V, Switch ON, See Figure 3	25°C	3.6V	-2	0.03	2	μA
			Full		-7		7	μA

DIGITAL CONTROL INPUTS (IN1, IN2, EN) (NOTE 2)

Input Logic High	V _{IH}		Full	3.6V	1.2		3.6	V
Input Logic Low	V _{IL}		Full	3.6V	0		0.65	V
Input leakage Current	I _{IH} , I _{IL}	V _i =V ₊ or 0	25°C	3.6V	-0.1	0.05	0.1	μA
			Full		-2.5		2.5	μA

DYNAMIC

Turn-on Time	T _{ON}	V _{COM} =V ₊ , R _L =50Ω, C _L =35pF, See Figure 5	25°C	3.3V		18.1	59	ns
			Full	3V~3.6V			60	ns
Turn-off Time	T _{OFF}	V _{COM} =V ₊ , R _L =50Ω, C _L =35pF, See Figure 5	25°C	3.3V		25.4	60.6	ns
			Full	3V~3.6V			61	ns
Break-before-make Time	T _{BBM}	V _{NC} =V _{NO} =V ₊ /2, R _L =50Ω, C _L =35pF, See Figure 6	25°C	3.3V	4	11.1	22.7	ns
			Full	3V~3.6V			28	ns
Charge Injection	Q _C	V _{GEN} =0, R _{GEN} =0, C _L =0.1nF, See Figure 10	25°C	3.3V		0.81		pC
NC, NO OFF Capacitance	C _{NC} (OFF), C _{NO} (OFF)	V _{NC} or V _{NO} =V ₊ or GND, Switch OFF, See Figure 4	25°C	3.3V		13		pF
COM OFF capacitance	C _{COM} (OFF)	V _{NC} or V _{NO} =V ₊ or GND, Switch OFF, See Figure 4		3.3V		8.5		pF
NC, NO ON Capacitance	C _{NC} (ON), C _{NO} (ON)	V _{NC} or V _{NO} =V ₊ or GND, Switch ON, See Figure 4	25°C	3.3V		21.5		pF
COM ON Capacitance	C _{COM} (ON)	V _{COM} =V ₊ or GND, Switch ON, See Figure 4	25°C	3.3V		21.5		pF
Digital Input Capacitance	C _I	V _i =V ₊ or GND, See Figure 4	25°C	3.3V		2		pF

■ ELECTRICAL CHARACTERISTICS FOR 3.3V SUPPLY (Cont.)

($V_+ = 3V \sim 3.6V$, $T = -40^\circ C \sim 85^\circ C$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Bandwidth	BW	$R_L = 50\Omega$, See Figure 7	$25^\circ C$	3.3V		240		MHz
OFF Isolation	O_{ISO}	$R_L = 50\Omega$, $f = 10MHz$, See Figure 8	$25^\circ C$	3.3V		-62		dB
Crosstalk	X_{TALK}	$R_L = 50\Omega$, $f = 1MHz$, See Figure 9	$25^\circ C$	3.3V		-62		dB
Crosstalk Adjacent	$X_{TALK (ADJ)}$	$R_L = 50\Omega$, $f = 10MHz$, See Figure 9	$25^\circ C$	3.3V		-71		dB
Total Harmonic Distortion	T_{HD}	$R_L = 600\Omega$, $C_L = 50pF$, $f = 20Hz \sim 20 kHz$, See Figure 11	$25^\circ C$	3.3V		0.05		%
SUPPLY								
Positive Supply Current	I_+	$V_i = V_+$ or GND, Switch ON or OFF	$25^\circ C$ Full	3.6V		0.04	0.3	μA
							3	μA

Notes: 1. The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

2. All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation.

ELECTRICAL CHARACTERISTICS FOR 2.5V SUPPLY (Note 1)
(V₊=2.3V~2.7V, T=-40°C~85°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
ANALOG SWITCH								
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}				0		V ₊	Ω
ON-state Resistance	R _{ON}	0≤(V _{NC} or V _{NO})≤V ₊ , I _{COM} =-32mA, Switch ON, See Figure 1	25°C	2.3V Full		5.5	9.6	Ω
			Full				11.5	Ω
ON-state Resistance Match Between Channels	ΔR _{ON}	V _{NC} or V _{NO} =1.6V, I _{COM} =-32mA, Switch ON, See Figure 1	25°C	2.3V Full		0.3	0.8	Ω
			Full				0.9	Ω
ON-state Resistance Flatness	R _{ON} (FLAT)	0≤(V _{NC} or V _{NO})≤V ₊ , I _{COM} =-32mA, Switch ON, See Figure 1	25°C	2.3V Full		0.91	2.2	Ω
			Full				2.3	Ω
NC, NO OFF Leakage Current	I _{NC} (OFF), I _{NO} (OFF)	V _{NC} or V _{NO} =0.5V, V _{COM} =2.3V, or V _{NC} or V _{NO} =2.3V, V _{COM} =0.5V, Switch OFF, See Figure 2	25°C	2.7V Full	-0.3	0.04	0.3	μA
			Full		-6		6	μA
	I _{NC} (PWROFF), I _{NO} (PWROFF)	V _{NC} or V _{NO} =0~2.7V, V _{COM} =2.7V~0, or V _{NC} or V _{NO} =2.7V~0, V _{COM} =0~2.7V, Switch OFF, See Figure 2	25°C	0V Full	-0.6	0.02	0.6	μA
			Full		-10		10	μA
COM OFF Leakage Current	I _{COM} (OFF)	V _{NC} or V _{NO} =0.5V, V _{COM} =2.3V, or V _{NC} or V _{NO} =2.3V, V _{COM} =0.5V, Switch OFF, See Figure 2	25°C	2.7V Full	-0.7	0.02	0.7	μA
			Full		-1		1	μA
	I _{COM} (PWROFF)	V _{NC} or V _{NO} =2.7V~0, V _{COM} =0~2.7V, or V _{NC} or V _{NO} =0~2.7V, V _{COM} =2.7V~0, Switch OFF, See Figure 2	25°C	0V Full	-0.7	0.02	0.7	μA
			Full		-7.2		7.2	
NC, NO ON Leakage Current	I _{NO} (ON), I _{NC} (ON)	V _{NC} or V _{NO} =0.5V or 2.3V, V _{COM} =Open, Switch ON, See Figure 3	25°C	2.7V Full	-2.1	0.03	2.1	μA
			Full		-6		6	μA
COM ON Leakage Current	I _{COM} (ON)	V _{NC} or V _{NO} =Open, V _{COM} =0.5V, or V _{NC} or V _{NO} =Open, V _{COM} =2.3V, Switch ON, See Figure 3	25°C	2.7V Full	-2	0.02	2	μA
			Full		-5.7		5.7	μA
DIGITAL CONTROL INPUTS (IN1, IN2, EN) (NOTE 2)								
Input Logic High	V _{IH}	V _i =V ₊ or GND	Full	2.7V	1.15		3.6	V
Input Logic Low	V _{IL}		Full	2.7V	0		0.55	V
Input Leakage Current	I _{IH} , I _{IL}	V _i =V ₊ or 0	25°C	2.7V Full	-0.1	0.01	0.1	μA
			Full		-2.1		2.1	μA

ELECTRICAL CHARACTERISTICS FOR 2.5V SUPPLY (Cont.)

($V_+ = 2.3V \sim 2.7V$, $T = -40^\circ C \sim 85^\circ C$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
DYNAMIC								
Turn-on time	T_{ON}	$V_{COM}=V_+$, $C_L=35pF$, $R_L=50\Omega$, See Figure 5	25°C	2.5V		17.2	36.8	ns
			Full	2.3V ~ 2.7V			42.5	ns
Turn-off time	T_{OFF}	$V_{COM}=V_+$, $C_L=35pF$, $R_L=50\Omega$, See Figure 5	25°C	2.5V		29.8	ns	
			Full	2.3V ~ 2.7V			34.4	ns
Break-before-make Time	T_{BBM}	$V_{NC}=V_{NO}=V_+/2$, $C_L=35pF$, $R_L=50\Omega$, See Figure 6	25°C	2.5V	4.5	13	30	ns
			Full	2.3V ~ 2.7V			33.3	ns
Charge Injection	Q_c	$V_{GEN}=0$, $C_L=0.1nF$, $R_{GEN}=0$, See Figure 10	25°C	2.5V		0.47		pC
NC, NO OFF Capacitance	$C_{NC\ (OFF)}$, $C_{NO\ (OFF)}$	V_{NC} or $V_{NO}=V_+$ or GND, Switch OFF, See Figure 4	25°C	2.5V		13.5		pF
COM OFF Capacitance	$C_{COM\ (OFF)}$	V_{NC} or $V_{NO}=V_+$ or GND, Switch OFF, See Figure 4	25°C	2.5V		9		pF
NC, NO ON Capacitance	$C_{NC\ (ON)}$, $C_{NO\ (ON)}$	V_{NC} or $V_{NO}=V_+$ or GND, Switch ON, See Figure 4	25°C	2.5V		22		pF
COM ON Capacitance	$C_{COM\ (ON)}$	$V_{COM}=V_+$ or GND, Switch ON, See Figure 4	25°C	2.5V		22		pF
Digital Input Capacitance	C_I	$V_I=V_+$ or GND, See Figure 4	25°C	2.5V		2		pF
Bandwidth	BW	$R_L=50\Omega$, Switch ON, See Figure 7	25°C	2.5V		240		MHz
OFF Isolation	O_{ISO}	$R_L=50\Omega$, $f=10MHz$, Switch OFF, See Figure 8	25°C	2.5V		-62		dB
Crosstalk	X_{TALK}	$R_L=50\Omega$, $f=10MHz$, Switch ON, See Figure 9	25°C	2.5V		-62		dB
Crosstalk Adjacent	$X_{TALK\ (ADJ)}$	$R_L=50\Omega$, $f=10MHz$, Switch ON, See Figure 9	25°C	2.5V		-71		dB
Total Harmonic Distortion	THD	$R_L=600\Omega$, $f=20Hz \sim 20kHz$, $C_L=50pF$, See Figure 11	25°C	2.5V		0.06		%
SUPPLY								
Positive Supply Current	I_+	$V_I=V_+$ or GND, Switch ON or OFF	25°C		0.01	0.1	μA	
			Full	2.7V		2	μA	

Notes: 1. The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

2. All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation.

■ ELECTRICAL CHARACTERISTICS FOR 1.8V SUPPLY (Note 1)

(V₊=1.65V~1.95V, T_A=-40°C~85°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
ANALOG SWITCH								
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}				0		V ₊	Ω
ON-state Resistance	R _{ON}	0≤(V _{NC} or V _{NO})≤V ₊ , I _{COM} =-32mA, Switch ON, See Figure 1	25°C	1.65V		7.1	14.4	Ω
			Full				16.3	Ω
ON-state Resistance Match Between Channels	ΔR _{ON}	V _{NC} or V _{NO} =1.6V, I _{COM} =-32mA, Switch ON, See Figure 1	25°C	1.65V		0.3	1	Ω
			Full				1.2	Ω
ON-state Resistance Flatness	R _{ON} (FLAT)	0≤(V _{NC} or V _{NO})≤V ₊ , I _{COM} =-32mA, Switch ON, See Figure 1	25°C	1.65V		2.7	5.5	Ω
			Full				7.3	Ω
NC, NO OFF Leakage Current	I _{NC} (OFF), I _{NO} (OFF)	V _{NC} or V _{NO} =0.3V, V _{COM} =1.65V, or V _{NC} or V _{NO} =1.65V, V _{COM} =0.3V, Switch OFF, See Figure 2	25°C	1.95V	-0.25	0.03	0.25	μA
			Full		-5		5	μA
	I _{NC} (PWROFF), I _{NO} (PWROFF)	V _{NC} or V _{NO} =1.95V~0, V _{COM} =0~1.95, or V _{NC} or V _{NO} =0~1.95V, V _{COM} =1.95V~0, Switch OFF, See Figure 2	25°C	0V	-0.4	0.02	0.4	μA
			Full		-7.2		7.2	μA
COM OFF Leakage Current	I _{COM} (OFF), I _{COM} (OFF)	V _{NC} or V _{NO} =0.3V, V _{COM} =1.65V, or V _{NC} or V _{NO} =1.65V, V _{COM} =0.3V, Switch OFF, See Figure 2	25°C	1.95V	-0.4	0.02	0.4	μA
			Full		-0.9		0.9	μA
	I _{COM} (PWROFF), I _{COM} (PWROFF)	V _{NC} or V _{NO} =1.95V~0, V _{COM} = 0~1.95V, or V _{NC} or V _{NO} =0~1.95V, V _{COM} =1.95V~0, Switch OFF, See Figure 2	25°C	0V	-0.4	0.02	0.4	μA
			Full		-5		5	μA
NC, NO ON Leakage Current	I _{NO} (ON), I _{NC} (ON)	V _{NC} or V _{NO} =0.3V, V _{COM} =Open, or V _{NC} or V _{NO} =1.65V, V _{COM} =Open, Switch ON, See Figure 3	25°C	1.95V	-2	0.02	2	μA
			Full		-5.2		5.2	μA
COM ON Leakage Current	I _{COM} (ON)	V _{NC} or V _{NO} =Open, V _{COM} =0.3V,or V _{NC} or V _{NO} =Open, V _{COM} =1.65V, Switch ON, See Figure 3	25°C	1.95V	-2	0.02	2	μA
			Full		-5.2		5.2	μA
DIGITAL CONTROL INPUTS (IN1, IN2, EN) (NOTE 2)								
Input Logic High	V _{IH}	V _I =V ₊ or GND	Full	1.95V	1		3.6	V
Input Logic Low	V _{IL}		Full	1.95V	0		0.4	V
Input Leakage Current	I _{IH} , I _{IL}	V _I =V ₊ or 0	25°C	1.95V	-0.1	0.01	0.1	μA
			Full		-2.1		2.1	μA

■ ELECTRICAL CHARACTERISTICS FOR 1.8V SUPPLY (Cont.)

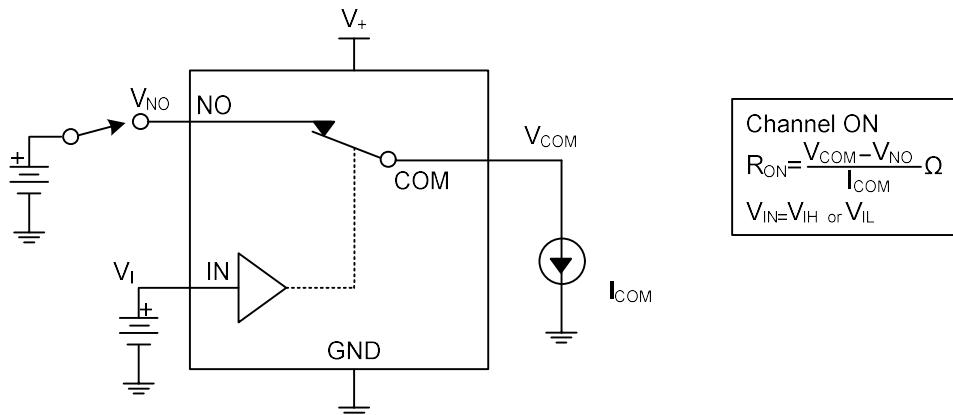
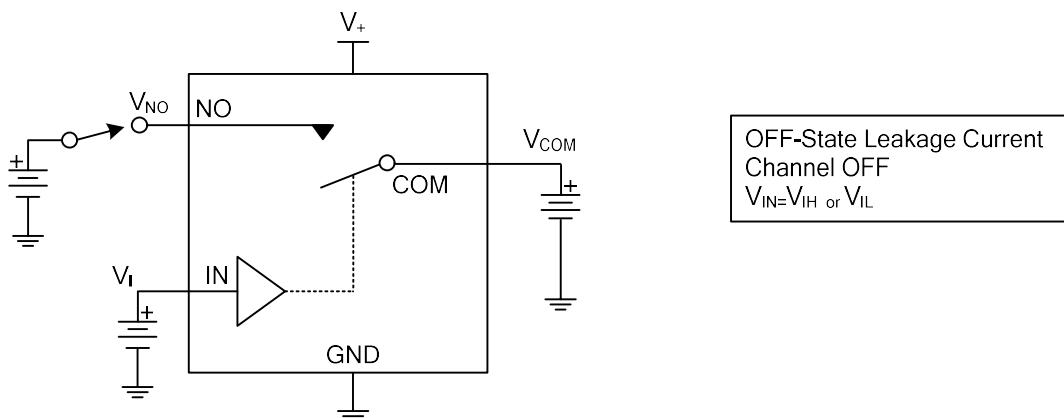
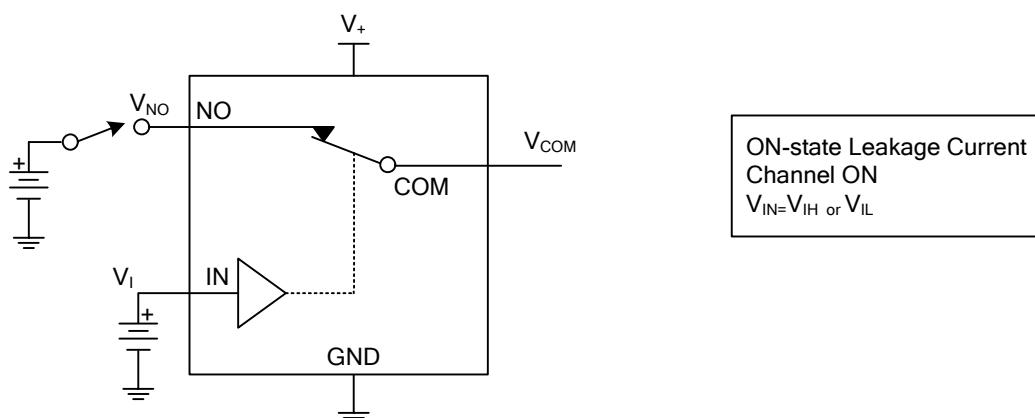
(V₊=1.65V~1.95V, T_A=-40°C~85°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
DYNAMIC								
Turn-on time	T _{ON}	V _{COM} =V ₊ , C _L =35pF, R _L =50Ω, See Figure 5	25°C	1.8V		14.1	49.3	ns
			Full	1.65V ~ 1.95V			56.7	ns
Turn-off time	T _{OFF}	V _{COM} =V ₊ , C _L =35pF, R _L =50Ω, See Figure 5	25°C	1.8V		16.1	26.5	ns
			Full	1.65V ~ 1.95V			31.2	ns
Break-before-make Time	T _{BBM}	V _{NC} =V _{NO} =V ₊ /2, C _L =35pF, R _L =50Ω, See Figure 6	25°C	1.8V	5.3	18.4	58	ns
			Full	1.65V ~ 1.95V			58	ns
Charge Injection	Q _C	V _{GEN} =0, C _L =1nF, R _{GEN} =0, See Figure 10	25°C	1.8V		0.21		pC
NC, NO OFF Capacitance	C _{NC (OFF)} , C _{NO (OFF)}	V _{NC} or V _{NO} =V ₊ or GND, Switch OFF, See Figure 4	25°C	1.8V		9		pF
NC, NO ON Capacitance	C _{NC (ON)} , C _{NO (ON)}	V _{NC} or V _{NO} =V ₊ or GND, Switch ON, See Figure 4	25°C	1.8V		22		pF
COM ON Capacitance	C _{COM (ON)}	V _{COM} =V ₊ or GND, Switch ON, See Figure 4	25°C	1.8V		22		pF
Digital Input Capacitance	C _I	V _I =V ₊ or GND, See Figure 4	25°C	1.8V		2		pF
Bandwidth	BW	R _L =50Ω, Switch ON, See Figure 7	25°C	1.8V		240		MHz
OFF Isolation	O _{ISO}	R _L =50Ω, f=10MHz, Switch OFF, See Figure 8	25°C	1.8V		-60		dB
Crosstalk	X _{TALK}	R _L =50Ω, f=10MHz, Switch ON, See Figure 9	25°C	1.8V		-60		dB
Crosstalk Adjacent	X _{TALK (ADJ)}	R _L =50Ω, f=10MHz, Switch ON, See Figure 9	25°C	1.8V		-71		dB
Total Harmonic Distortion	THD	R _L =600Ω, f=20Hz~20kHz, C _L =50pF, See Figure 11	25°C	1.8V		0.1		%
SUPPLY								
Positive Supply Current	I ₊	V _I =V ₊ or GND, Switch ON or OFF	25°C			0.01	0.1	μA
			Full	1.95V			1.5	μA

Notes: 1. The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

2. All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation.

■ PARAMETER MEASUREMENT INFORMATION

Figure 1. ON-state Resistance (R_{ON})Figure 2. OFF-State Leakage Current
 $(I_{COM(OFF)}, I_{NC(OFF)}, I_{COM(PWROFF)}, I_{NC(PWROFF)})$ Figure 3. ON-state Leakage Current
 $(I_{COM(ON)}, I_{NC(ON)})$

■ PARAMETER MEASUREMENT INFORMATION (Cont.)

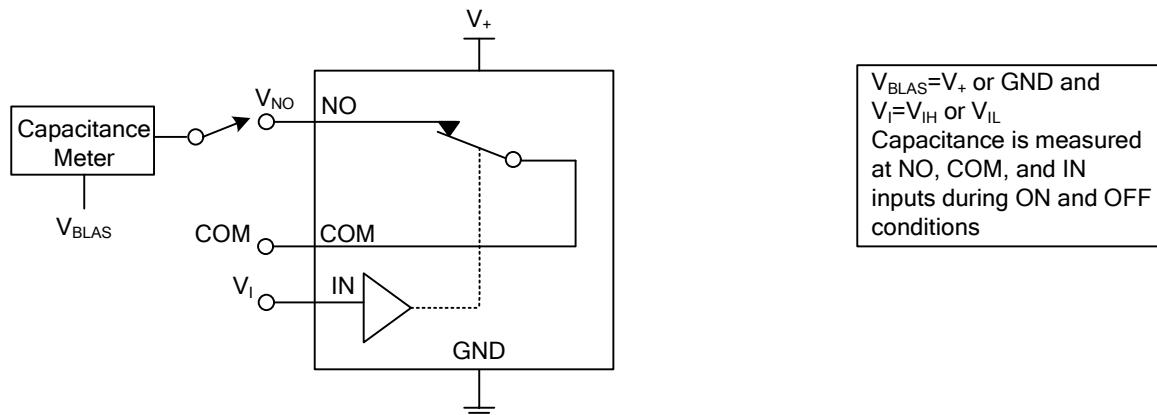
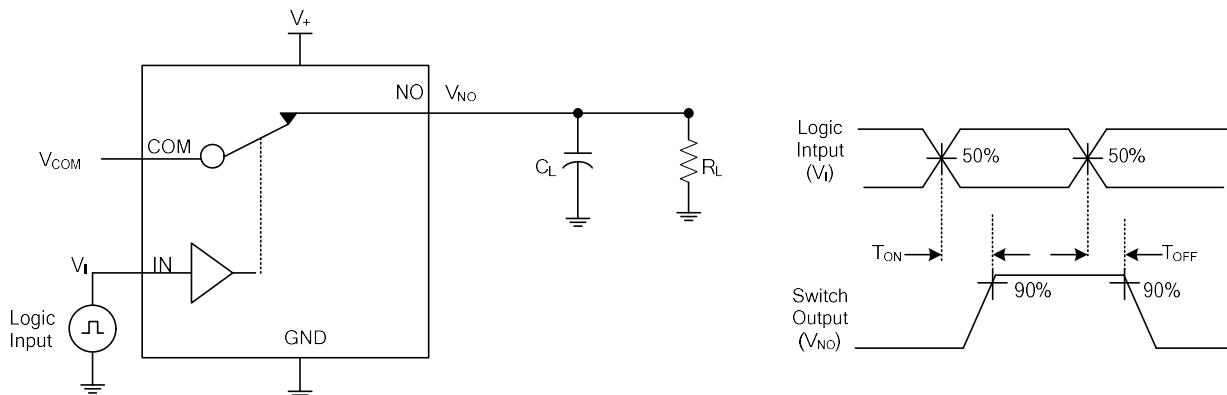


Figure 4. Capacitance
 $(C_I, C_{COM \text{ (OFF)}}, C_{COM \text{ (ON)}}, C_{NC \text{ (OFF)}}, C_{NC \text{ (ON)}})$

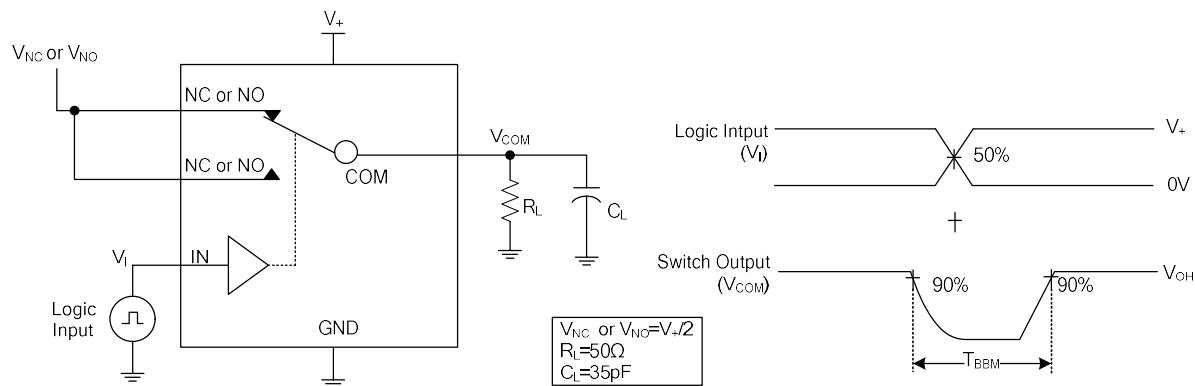
TEST	R_L	C_L	V_{COM}
T_{ON}	50Ω	35pF	V_+
T_{OFF}	50Ω	35pF	V_+



Note 1: All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, $Z_0=50\Omega$, $T_R<5\text{ns}$, $T_F<5\text{ns}$.
 Note 2: C_L includes probe and jig capacitance.

Figure 5. Turn-On (T_{ON}) and Turn-Off Time (T_{OFF})

■ PARAMETER MEASUREMENT INFORMATION (Cont.)



Note 1: All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, $Z_o=50\Omega$, $T_R<5ns$, $T_F<5ns$.
Note 2: C_L includes probe and jig capacitance.

Figure 6. Break-Before-Make Time (T_{BBM})

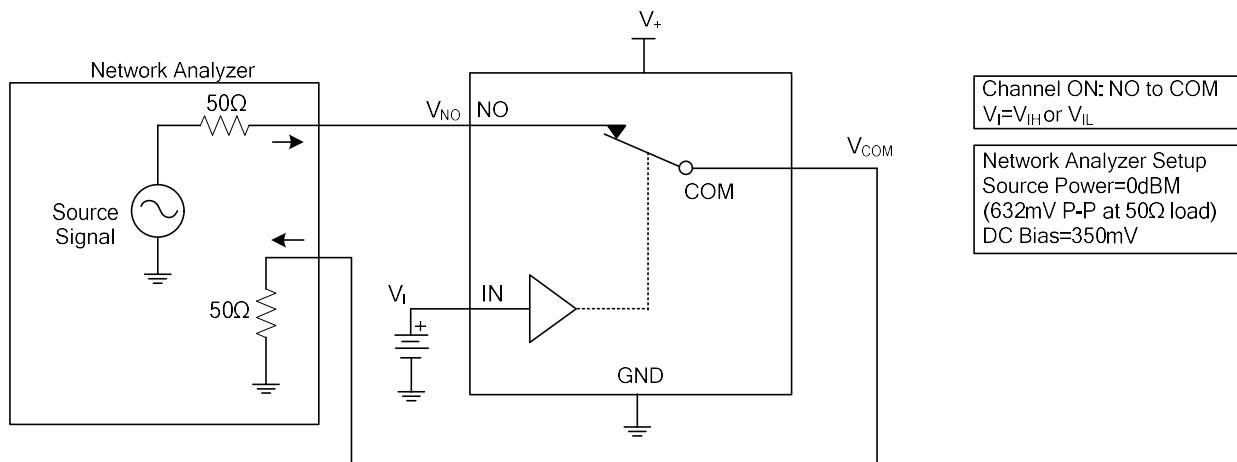
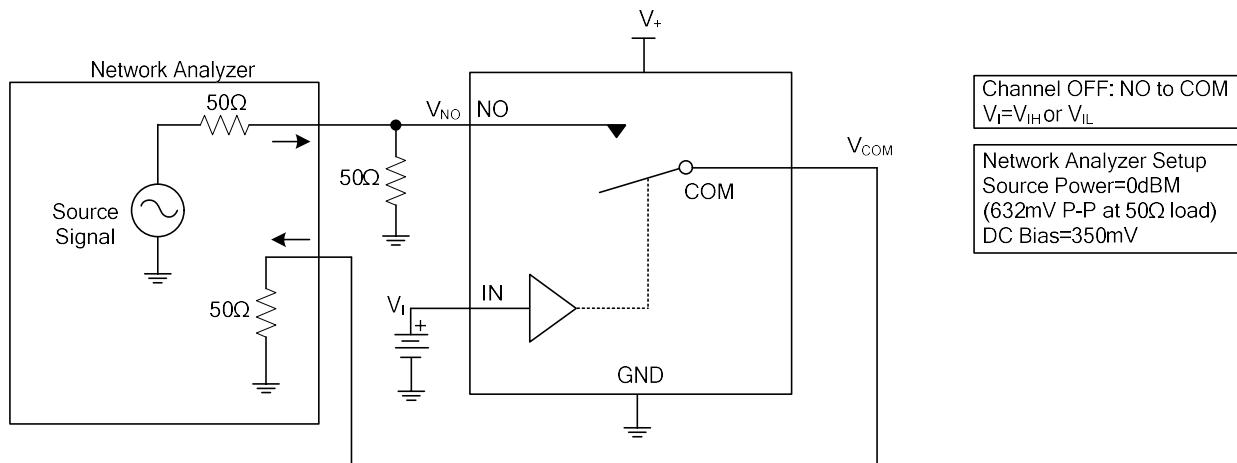
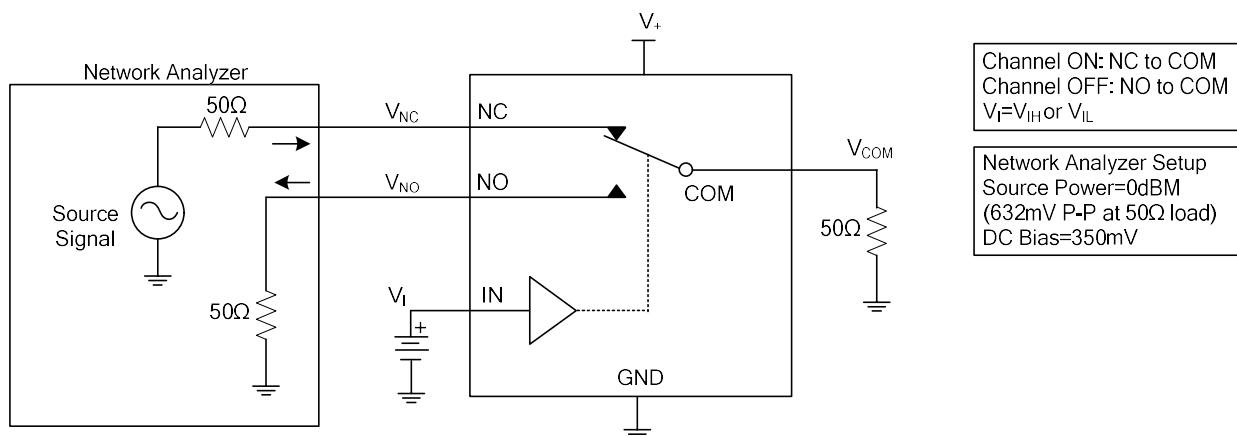
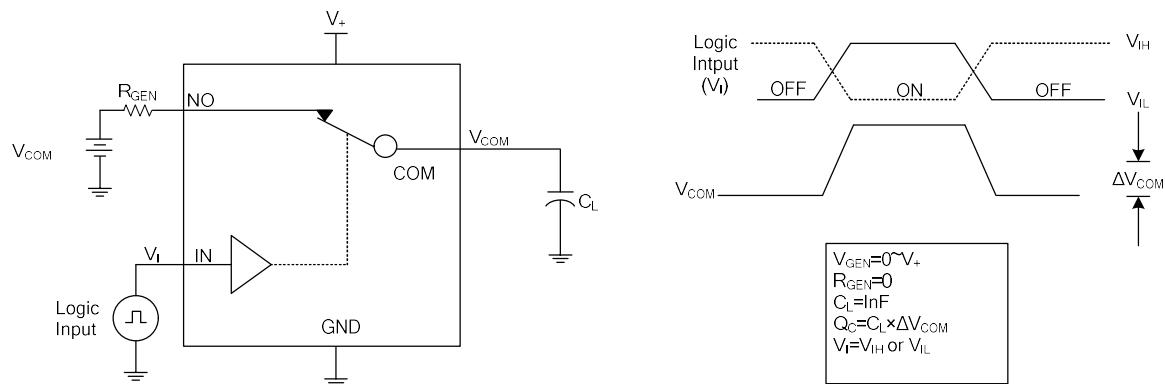


Figure 7. Bandwidth (BW)

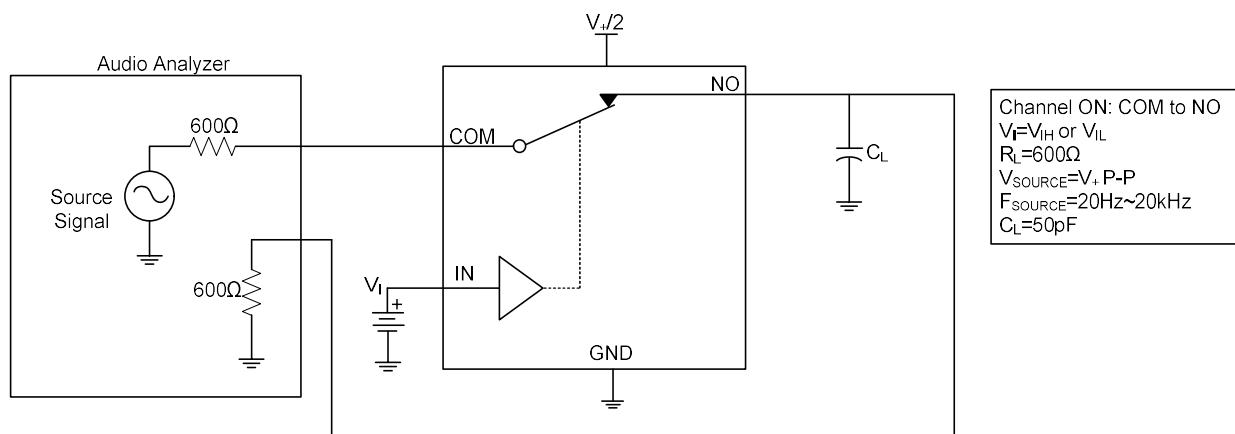
■ PARAMETER MEASUREMENT INFORMATION (Cont.)

Figure 8. OFF Isolation (O_{ISO})Figure 9. Crosstalk (X_{TALK})

■ PARAMETER MEASUREMENT INFORMATION (Cont.)

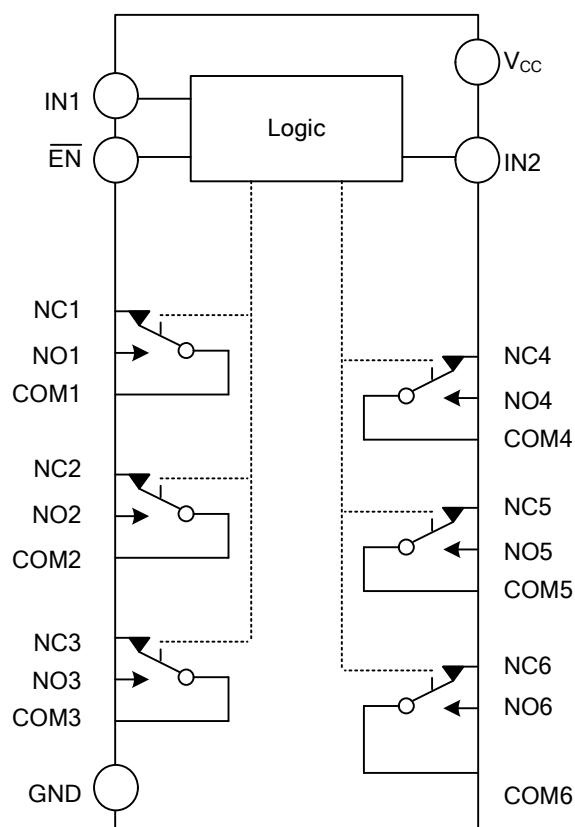


Note 1: All input pulses are supplied by generators having the following characteristics: PRR $\leq 10\text{MHz}$, $Z_0 = 50\Omega$, $T_F \leq 5\text{ns}$, $T_R \leq 5\text{ns}$.
Note 2: C_L includes probe and jig capacitance.

Figure 10. Charge Injection (Q_C)

Note: C_L includes probe and jig capacitance.

Figure 11. Total Harmonic Distortion (THD)

■ TYPICAL APPLICATION CIRCUIT

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